Nch 60V 8A Power MOSFET

| V _{DSS} | 60V |
|----------------------------|------|
| R _{DS(on)} (Max.) | 80mΩ |
| I _D | ±8A |
| P_D | 15W |

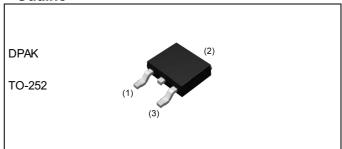
Features

- 1) Low on resistance.
- 2) Fast switching speed.
- 3) Drive circuits can be simple.
- 4) Parallel use is easy.
- 5) Pb-free lead plating; RoHS compliant

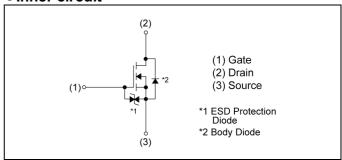
Application

Switching

Outline



●Inner circuit



Packaging specifications

| | Packing | Embossed Tape |
|------|---------------------------|------------------|
| | Reel size (mm) | 330 |
| _ | Tape width (mm) | 16 |
| Type | Basic ordering unit (pcs) | 2500 |
| | Taping code | TL |
| | raping code | TL1 |
| | Marking | RD3L080SN |

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

| Parameter | Symbol | Value | Unit |
|--|--------------------|-------------|------|
| Drain - Source voltage | V _{DSS} | 60 | V |
| Continuous drain current | I _D *1 | ±8 | Α |
| Pulsed drain current | I _{DP} *2 | ±16 | Α |
| Gate - Source voltage | V _{GSS} | ±20 | V |
| Power dissipation | P _D *3 | 15 | W |
| Junction temperature | Tj | 150 | °C |
| Operating junction and storage temperature range | T _{stg} | -55 to +150 | °C |

●Thermal resistance

| Parameter | Symbol | Values | | | l leit |
|-------------------------------------|----------------------|--------|------|------|--------|
| Parameter | Symbol | Min. | Тур. | Max. | Unit |
| Thermal resistance, junction - case | R _{thJC} *3 | - | - | 8.33 | °C/W |

● Electrical characteristics (T_a = 25°C)

| Doromotor | Symbol | Symbol Conditions | | Values | | | |
|---|---|--|------|--------|------|-------|--|
| Parameter Sym | | Conditions | Min. | Тур. | Max. | Unit | |
| Drain - Source breakdown voltage | V _{(BR)DSS} | V _{GS} = 0V, I _D = 1mA | 60 | - | - | V | |
| Breakdown voltage temperature coefficient | $\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$ | I _D = 1mA referenced to 25°C | - | 63.7 | - | mV/°C | |
| Zero gate voltage drain current | I _{DSS} | V _{DS} = 60V, V _{GS} = 0V | - | - | 1 | μA | |
| Gate - Source leakage current | I _{GSS} | $V_{GS} = \pm 20V, V_{DS} = 0V$ | - | 1 | ±10 | μA | |
| Gate threshold voltage | $V_{GS(th)}$ | V _{DS} = 10V , I _D = 1mA | 1.0 | 1 | 2.5 | V | |
| Gate threshold voltage temperature coefficient | $\frac{\Delta V_{GS(th)}}{\Delta T_{j}}$ | I _D = 1mA referenced to 25°C | - | -4.4 | - | mV/°C | |
| | | V _{GS} = 10V, I _D = 8A | - | 57 | 80 | | |
| Static drain - source on - state resistance | R _{DS(on)} *4 | V _{GS} = 4.5V, I _D = 8A | - | 70 | 98 | mΩ | |
| | | $V_{GS} = 4.0V, I_D = 8A$ | - | 78 | 109 | | |
| Gate resistance R _G f = 1MHz, open drain | | - | 9.4 | - | Ω | | |
| Forward Transfer Admittance | Y _{fs} *4 | V _{DS} = 10V, I _D = 8A | 4.8 | - | - | S | |

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10 μ s , Duty cycle \leq 1%

^{*3} T_C=25°C

^{*4} Pulsed

●Electrical characteristics (T_a = 25°C)

| Darameter | Cymala al | Conditions | Values | | | l lm:4 | |
|------------------------------|------------------------|-----------------------------------|--------|------|------|--------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit | |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 380 | - | _ | |
| Output capacitance | C _{oss} | V _{DS} = 10V | - | 90 | - | pF | |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 50 | - | | |
| Turn - on delay time | t _{d(on)} *4 | $V_{DD} \simeq 30V, V_{GS} = 10V$ | - | 9 | - | | |
| Rise time | t _r *4 | I _D = 4A | - | 13 | - | no | |
| Turn - off delay time | t _{d(off)} *4 | $R_L \simeq 7.5\Omega$ | - | 30 | - | ns | |
| Fall time | t _f *4 | $R_G = 10\Omega$ | - | 10 | - | | |

● Gate charge characteristics (T_a = 25°C)

| Doromotor | Symbol Conditions | | Values | | | 1.1:4 |
|----------------------|--------------------|------------------------|--------|------|------|-------|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
| Total gate charge | Qg*4 | V _{DD} ≃ 30V, | - | 9.4 | - | |
| Gate - Source charge | Q _{gs} *4 | $I_D = 8A$, | - | 1.8 | - | nC |
| Gate - Drain charge | Q _{gd} *4 | V _{GS} = 10V | - | 2.3 | - | |

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

| Darameter | Symbol | Conditions | Values | | | l leit | |
|----------------------------|--------------------|---|--------|------|------|--------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit | |
| Continuous forward current | I _S *1 | T = 25°C | - | - | 8 | Α | |
| Pulse forward current | I _{SP} *2 | T _a = 25°C | - | - | 16 | Α | |
| Forward voltage | V _{SD} *4 | V _{GS} = 0V, I _S = 8A | - | - | 1.5 | V | |

Fig.1 Power Dissipation Derating Curve

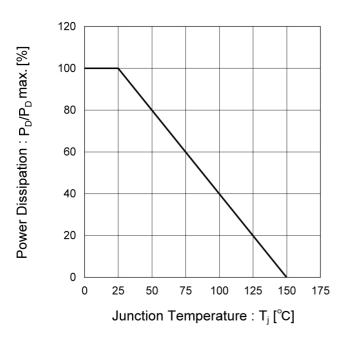


Fig.2 Maximum Safe Operating Area

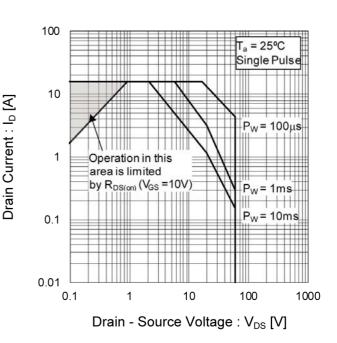


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

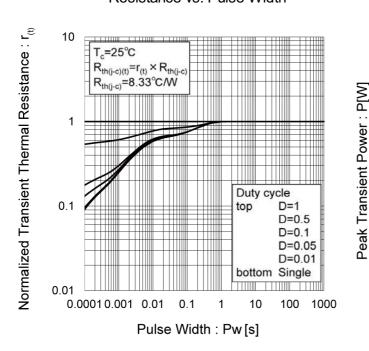


Fig.4 Single Pulse Maximum Power dissipation

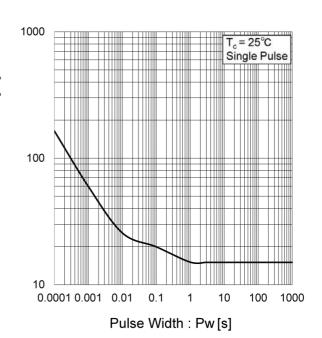
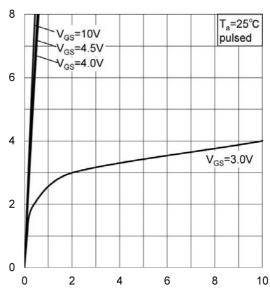


Fig.5 Typical Output Characteristics(I)

T_a=25°C pulsed 6 Drain Current : I_D [A] V_{GS}=10V V_{GS}=4.5V V_{GS}=4.0V 2 V_{GS}=3.0V 0 0.2 0.4 0.6 0.8 0 Drain - Source Voltage: V_{DS} [V]

Fig.6 Typical Output Characteristics(II)



Drain Current : I_D [A]

Drain - Source Voltage : V_{DS} [V]

Fig.7 Breakdown Voltage vs.
Junction Temperature

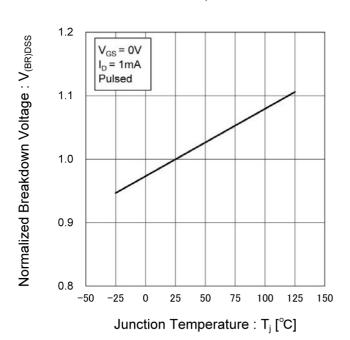


Fig.8 Typical Transfer Characteristics

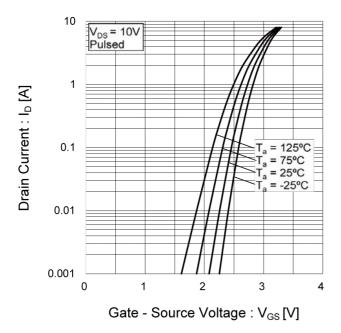


Fig.9 Gate Threshold Voltage vs.

Junction Temperature

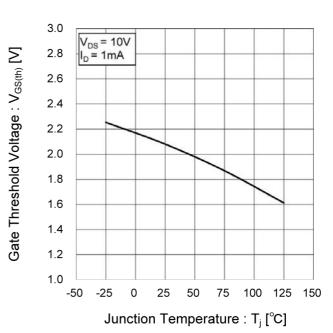


Fig.10 Forward Transfer Admittance vs.
Drain Current

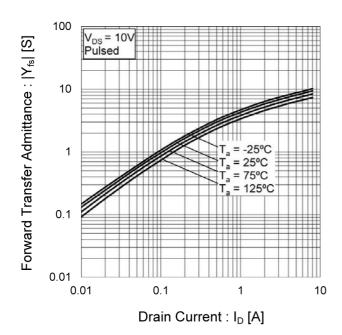


Fig.11 Drain Current Derating Curve

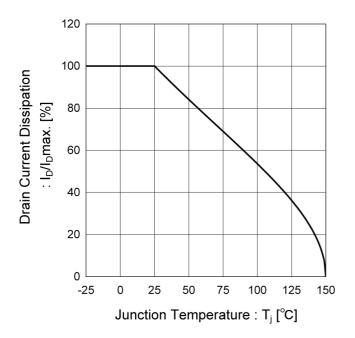


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

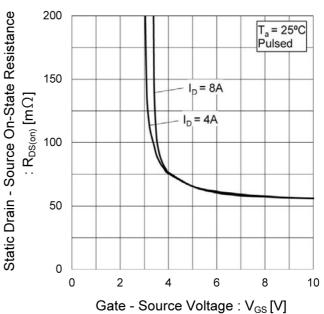
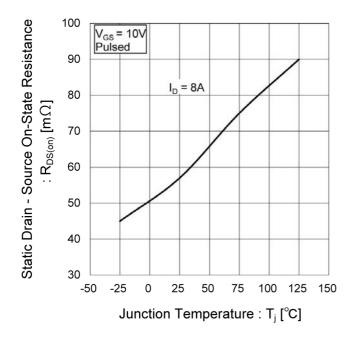


Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature



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Fig.14 Static Drain - Source On - State Resistance vs. Drain Current(I)

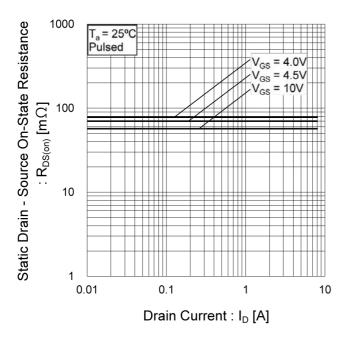


Fig.15 Static Drain - Source On - State
Resistance vs. Drain Current(II)

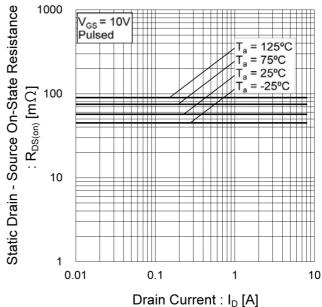


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current(III)

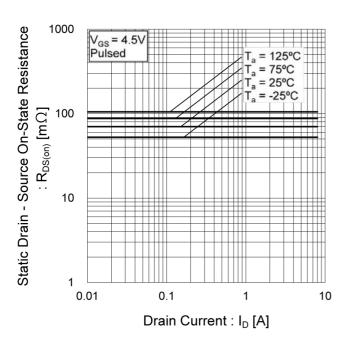


Fig.17 Static Drain - Source On - State Resistance vs. Drain Current(IV)

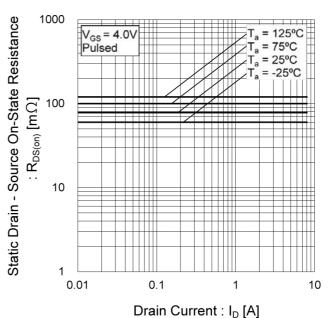


Fig.18 Typical Capacitance vs.

Drain - Source Voltage

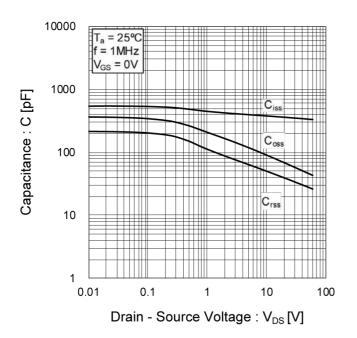


Fig.19 Switching Characteristics

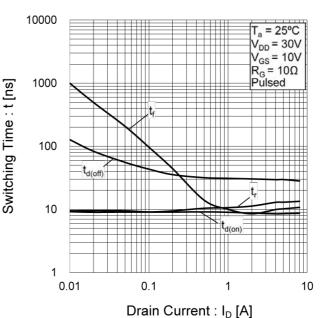


Fig.20 Dynamic Input Characteristics

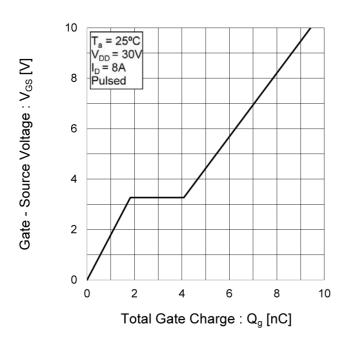
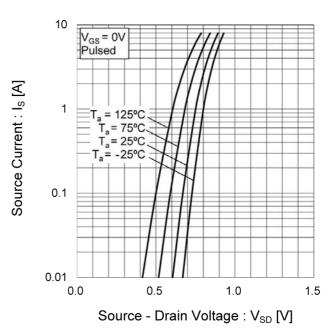


Fig.21 Source Current vs.

Source Drain Voltage



Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

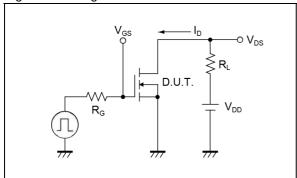


Fig.2-1 Gate Charge Measurement Circuit

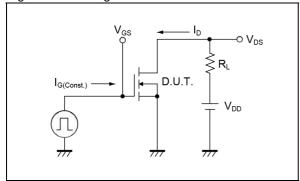


Fig.1-2 Switching Waveforms

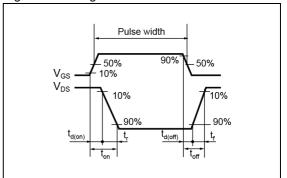
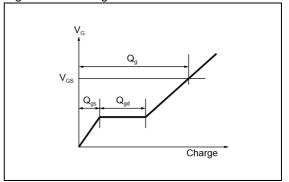
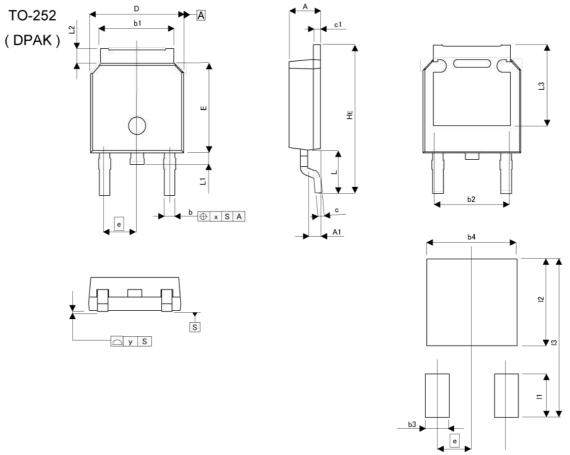


Fig.2-2 Gate Charge Waveform



ullet Dimensions (TL)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

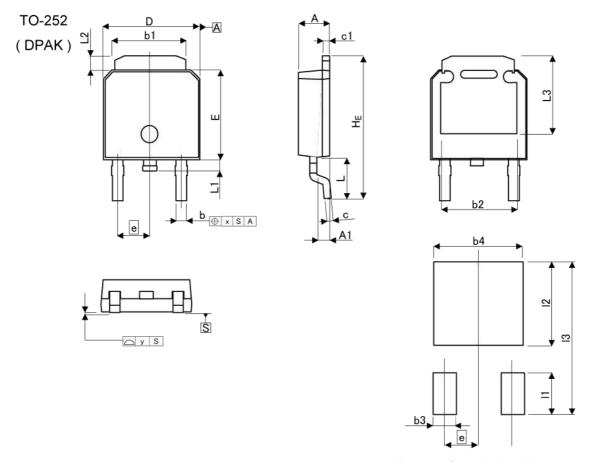
| DIM - | MILIME | ETERS | INC | HES | |
|-------|--------|-------|-------|-------|--|
| DIIVI | MIN | MAX | MIN | MAX | |
| Α | 2.10 | 2.30 | 0.083 | 0.091 | |
| A1 | 0.70 | 1.10 | 0.028 | 0.043 | |
| b | 0.65 | 0.85 | 0.026 | 0.033 | |
| b1 | 5.10 | 5.40 | 0.201 | 0.213 | |
| b2 | 5. | 10 | 0.2 | 201 | |
| С | 0.40 | 0.60 | 0.016 | 0.024 | |
| c1 | 0.40 | 0.60 | 0.016 | 0.024 | |
| D | 6.40 | 6.80 | 0.252 | 0.268 | |
| е | 2. | 30 | 0.091 | | |
| E | 6.00 | 6.40 | 0.236 | 0.252 | |
| HE | 9.50 | 10.50 | 0.374 | 0.413 | |
| L | 2. | 90 | 0.1 | 14 | |
| L1 | 0.70 | 0.90 | 0.028 | 0.035 | |
| L2 | 0.70 | 1.30 | 0.028 | 0.051 | |
| L3 | 5.30 | | 0.209 | | |
| х | - | 0.10 | 161 | 0.004 | |
| у | - | 0.10 | - | 0.004 | |

| DIM | MILIMETERS | | INC | HES | |
|-----|------------|-------|-------------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| b3 | <i>E</i> | 1.10 | 622 | 0.043 | |
| b4 | * | 5.40 | 5 .0 5 | 0.213 | |
| I1 | <u> </u> | 2.90 | 721 | 0.114 | |
| 12 | * | 5.50 | 5.0 | 0.217 | |
| 13 | 2 | 10.50 | 021 | 0.413 | |

Dimension in mm/inches



● Dimensions (TL1)



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

| DIM - | MILIME | ETERS | INCI | HES |
|-------|--------|-------|--------------|-------|
| DIIVI | MIN | MAX | MIN | MAX |
| Α | 2.20 | 2.40 | 0.087 | 0.094 |
| A1 | 0.70 | 1.10 | 0.028 | 0.043 |
| b | 0.60 | 0.90 | 0.024 | 0.035 |
| b1 | 5.20 | 5.50 | 0.205 | 0.217 |
| b2 | 4. | 80 | 0.1 | 89 |
| С | 0.40 | 0.60 | 0.016 | 0.024 |
| c1 | 0.40 | 0.60 | 0.016 | 0.024 |
| D | 6.40 | 6.80 | 0.252 | 0.268 |
| е | 2.30 | | 0.0 | 91 |
| E | 6.00 | 6.40 | 0.236 | 0.252 |
| HE | 9.40 | 10.40 | 0.370 | 0.409 |
| L | 2. | 90 | 0.114 | |
| L1 | 0.60 | 1.00 | 0.024 | 0.039 |
| L2 | 0.70 | 1.30 | 0.028 | 0.051 |
| L3 | 5. | 30 | 0.209 | |
| х | ÷ | 0.25 | X (#) | 0.010 |
| у | 8 | 0.10 | (5) | 0.004 |
| - T | MILIME | TERS | INCHES | |
| DIM | MIN | MAX | MIN | MAX |
| b3 | ¥] | 1.15 | 9 ± 3 | 0.045 |
| b4 | - | 5.55 | 0.75) | 0.219 |
| 11 | - | 2.77 | S (#3) | 0.109 |
| 12 | 8 | 5.50 | (8) | 0.217 |
| 13 | # | 10.40 | 7E0 | 0.409 |

Dimension in mm/inches



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- 8. Confirm that operation temperature is within the specified range described in the product specification.
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 - [d] the Products are exposed to high Electrostatic
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